



SGMNT19360

60V, Power, Single N-Channel, PDFN Package, MOSFET

FEATURES

- Low On-State Resistance
- Low Total Gate Charge and Capacitance Losses
- RoHS Compliant and Halogen Free

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNITS
Drain-to-Source Voltage	V_{DS}	60	V
Gate-to-Source Voltage	V_{GS}	± 20	V
Drain Current ⁽¹⁾	I_D	$T_C = +25^\circ\text{C}$	29
		$T_C = +100^\circ\text{C}$	18
		$T_A = +25^\circ\text{C}$	7.9
		$T_A = +70^\circ\text{C}$	6.3
Drain Current (Pulse) ⁽²⁾	I_{DM}	72	A
Total Dissipation	P_D	$T_C = +25^\circ\text{C}$	36
		$T_C = +100^\circ\text{C}$	14
		$T_A = +25^\circ\text{C}$	2.2
		$T_A = +70^\circ\text{C}$	1.4
Avalanche Current ⁽³⁾	I_{AS}	28.1	A
Avalanche Energy ⁽³⁾	E_{AS}	39.5	mJ
Junction Temperature	T_J	+150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150	$^\circ\text{C}$
Lead Temperature (Soldering, 10s)		+260	$^\circ\text{C}$

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

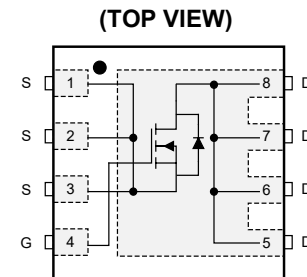
NOTES:

1. The current will be limited by package, PCB, thermal design and operating temperature.
2. $t_{PULSE} < 10\mu\text{s}$.
3. Parts are 100% tested at $V_{GS} = 10\text{V}$, $I_L = 20\text{A}$, and $E_{AS} = 20\text{mJ}$.

PRODUCT SUMMARY

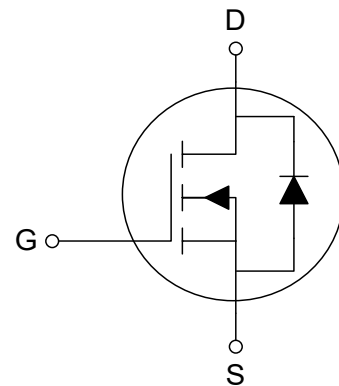
$R_{DS(on)}$ (TYP) $V_{GS} = 10\text{V}$	$R_{DS(on)}$ (MAX) $V_{GS} = 10\text{V}$	I_D (MAX) $T_C = +25^\circ\text{C}$
15m Ω	20m Ω	29A

PIN CONFIGURATION



PDFN-3.3x3.3-8AL

EQUIVALENT CIRCUIT



APPLICATIONS

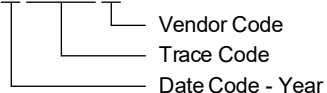
Ultra-High Performance Power Switching
Motors, Lamps and Solenoid Control
Transmission Control
DC/DC System

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGMNT19360	PDFN-3.3×3.3-8AL	-55°C to +150°C	SGMNT19360TPDB8G/TR	SGM203 TPDB8 XXXXX	Tape and Reel, 5000

MARKING INFORMATION

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.

XXXXX

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

THERMAL RESISTANCE

PARAMETER	SYMBOL	TYP	UNITS
Junction-to-Case Thermal Resistance	$R_{\theta JC}$	3.8	°C/W
Junction-to-Ambient Thermal Resistance ⁽¹⁾	$R_{\theta JA}$	56	°C/W

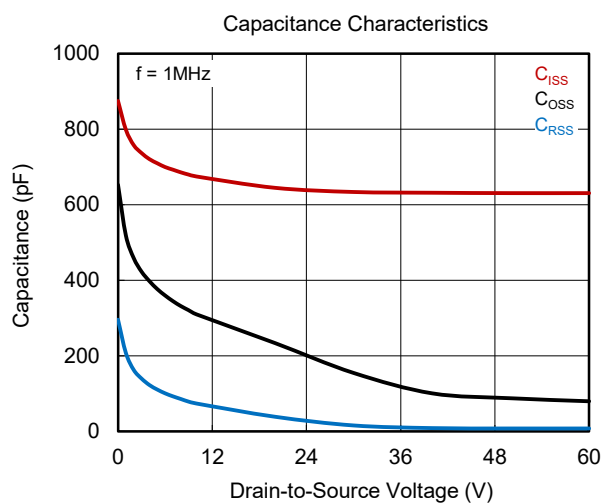
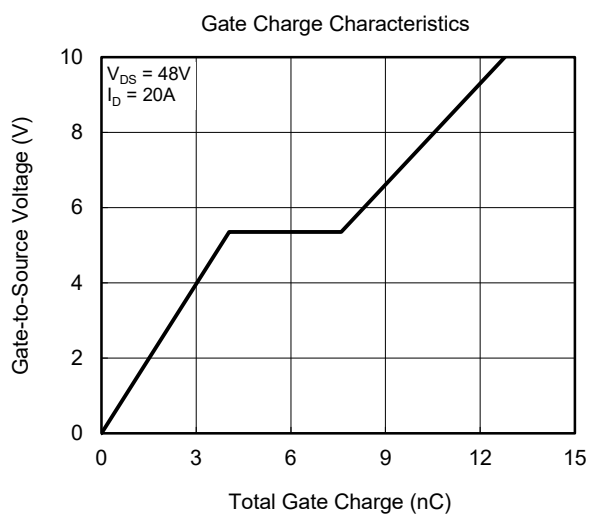
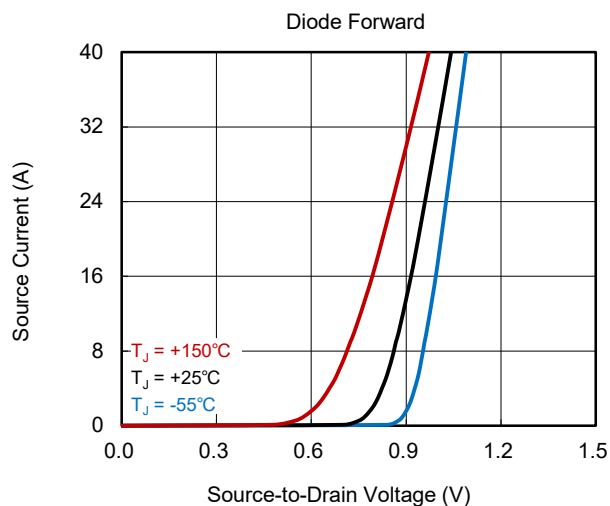
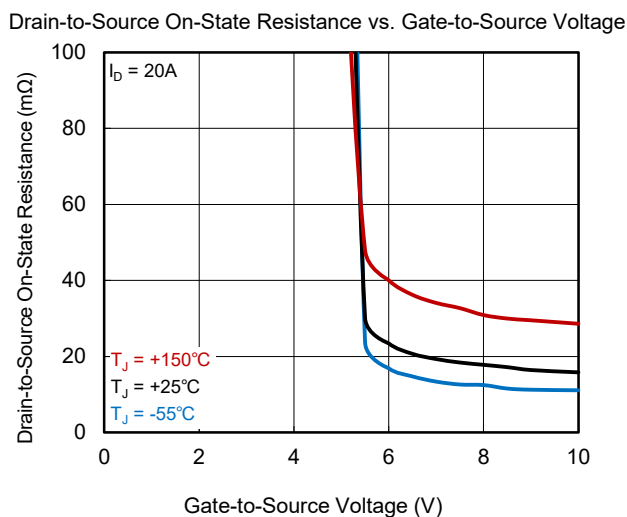
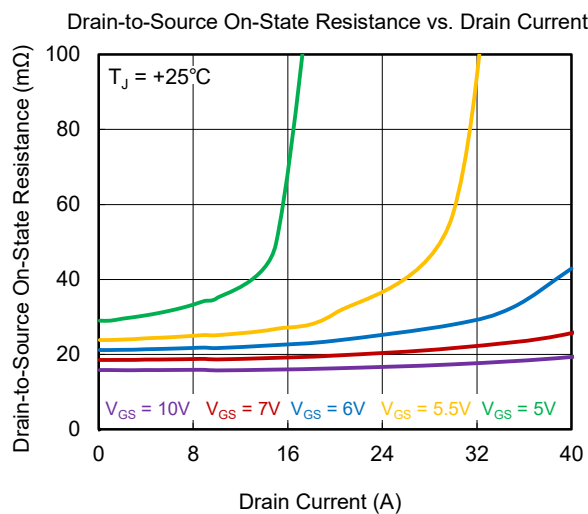
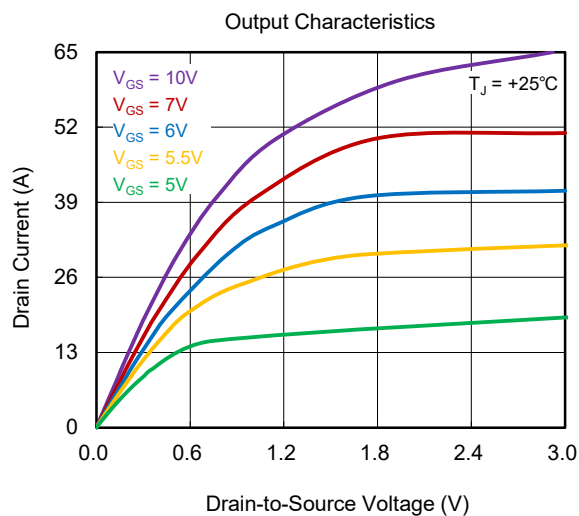
NOTE: 1. $R_{\theta JA}$ is determined with the device mounted on one square inch of copper pad, 2oz copper on FR4 board.

ELECTRICAL CHARACTERISTICS

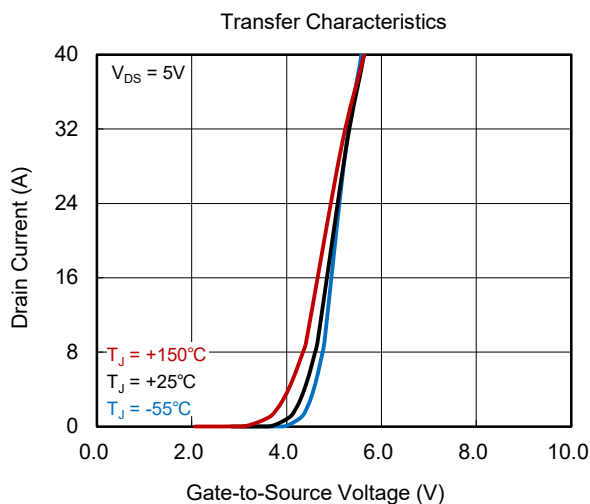
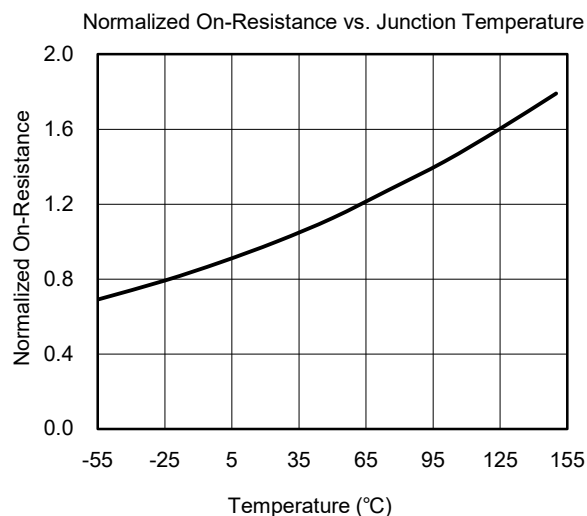
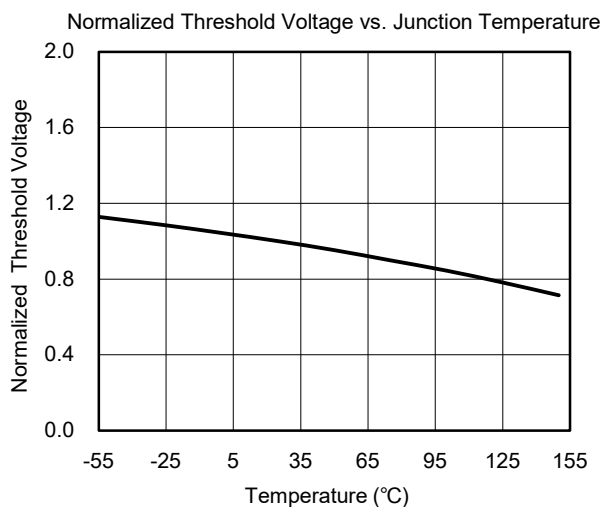
(T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Static OFF Characteristics						
Drain-to-Source Breakdown Voltage	V _{BR_DSS}	V _{GS} = 0V, I _D = 250μA	60			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0V, V _{DS} = 48V			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V			±100	nA
Static ON Characteristics						
Gate-to-Source Threshold Voltage	V _{GS_TH}	V _{GS} = V _{DS} , I _D = 250μA	2	2.8	4	V
Drain-to-Source On-State Resistance	R _{DSON}	V _{GS} = 10V, I _D = 20A		15	20	mΩ
Forward Transconductance	g _{fs}	V _{DS} = 5V, I _D = 20A		13		S
Gate Resistance	R _G	V _{GS} = 0V, V _{DS} = 0V, f = 1MHz		1		Ω
Diode Characteristics						
Diode Forward Voltage	V _{F_SD}	V _{GS} = 0V, I _S = 20A		0.9	1.2	V
Reverse Recovery Time	t _{RR}	V _{GS} = 0V, I _S = 20A, di/dt = 100A/μs		18		ns
Reverse Recovery Charge	Q _{RR}			11		nC
Dynamic Characteristics						
Input Capacitance	C _{ISS}	V _{GS} = 0V, V _{DS} = 30V, f = 1MHz		693		pF
Output Capacitance	C _{OSS}			148		
Reverse Transfer Capacitance	C _{RSS}			15		
Total Gate Charge	Q _G	V _{GS} = 10V, V _{DS} = 48V, I _D = 20A		12.8		nC
Gate-to-Source Charge	Q _{GS}			4.1		
Gate-to-Drain Charge	Q _{GD}			3.5		
Switch Characteristics						
Turn-On Delay Time	t _{D_ON}	V _{GS} = 10V, V _{DS} = 48V, I _D = 20A, R _G = 3Ω		5.7		ns
Rise Time	t _R			29.9		
Turn-Off Delay Time	t _{D_OFF}			9.8		
Fall Time	t _F			16.8		

TYPICAL PERFORMANCE CHARACTERISTICS



TYPICAL PERFORMANCE CHARACTERISTICS (continued)



REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

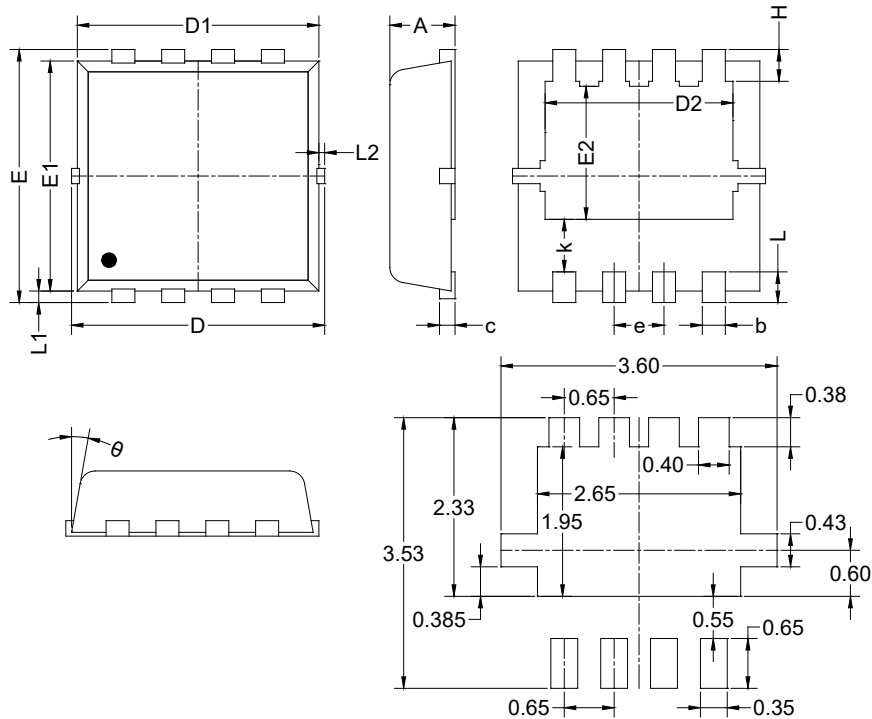
Changes from Original to REV.A (SEPTEMBER 2025)

Page

Changed from product preview to production data.....All

PACKAGE OUTLINE DIMENSIONS

PDFN-3.3×3.3-8AL



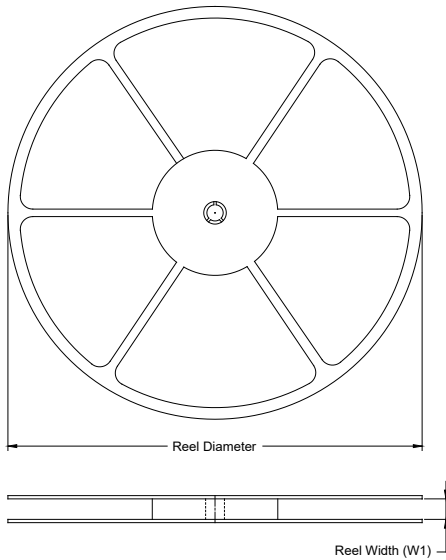
RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	Dimensions In Millimeters		
	MIN	NOM	MAX
A	0.700	0.800	0.900
b	0.250	0.300	0.350
c	0.140	0.150	0.200
D	3.100	3.300	3.500
D1	3.050	3.150	3.250
D2	2.350	2.450	2.550
E	3.100	3.300	3.500
E1	2.900	3.000	3.100
E2	1.640	1.740	1.840
e	0.650 BSC		
H	0.320	0.420	0.520
k	0.590	0.690	0.790
L	0.250	0.400	0.550
L1	0.100	0.150	0.200
L2	-	-	0.150
θ	8°	10°	12°

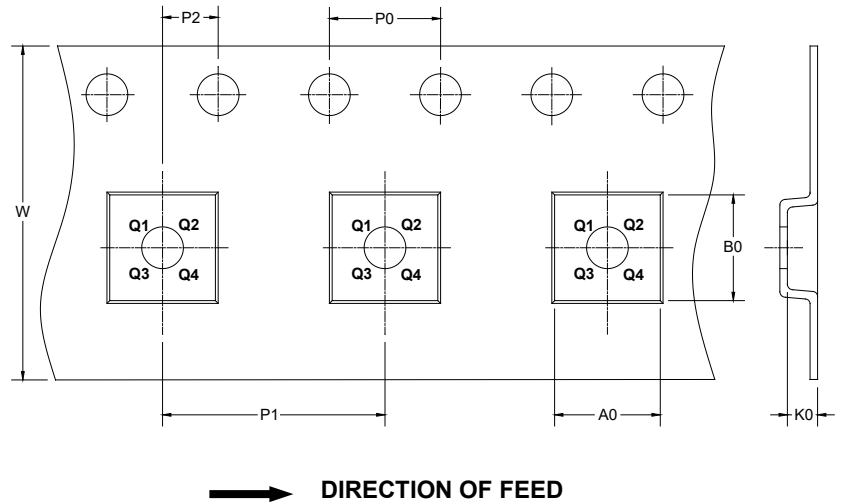
NOTE: This drawing is subject to change without notice.

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

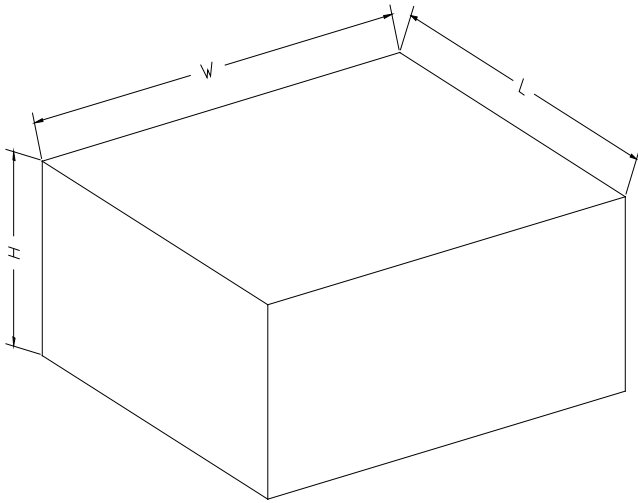
KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
PDFN-3.3×3.3-8AL	13"	12.4	3.60	3.60	1.10	4.0	8.0	2.0	12.0	Q1

DD00001

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13"	386	280	370	5

DD0002